NSN 5961-00-284-6998

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-284-6998 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-71 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor and 4.5 gate to source cutoff voltage all transistor **Current Rating Per Characteristic:** 5.00 milliamperes average forward current averaged over a full 60-hz cycle all transistor **Power Rating Per Characteristic:** 250.0 milliwatts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Item must comply with requirements of defense electronics supply center production standard no. L01386; for navy nuclear propulsion plant products only **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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